ABSTRACT OF THE DISCLOSURE

A surface acoustic wave device includes a quartz substrate having Euler angles (0°, θ, 90° ± 5°) in which θ is in a range of 119° ≤ θ ≤ 140°, and an IDT for exciting an SH wave is formed on the quartz substrate by use of an electrode material containing as a major component at least one of Ag, Mo, Cu, Ni, Cr, and Zn and having a density of at least about 7g/cm^3. The film thickness of the IDT is such that the attenuation constant is approximately zero.

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